2SK1762

Silicon N-Channel MOS FET

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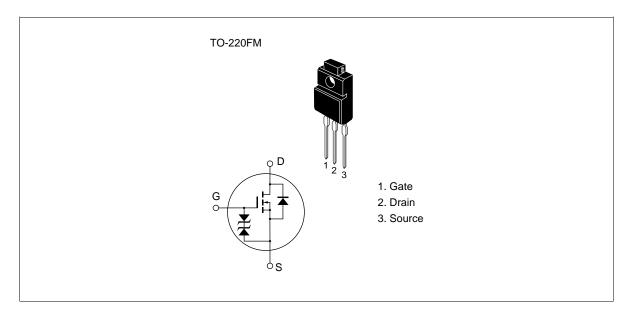
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switchingregulator, DC-DC converter

Outline





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Absolute Maximum Ratings (Ta = 25° C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	250	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	12	А
Drain peak current	L _{D(pulse)} *1	48	А
Body to drain diode reverse drain current	I _{DR}	12	А
Channel dissipation	Pch*2	35	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes 1. PW 10 µs, duty cycle 1 %

2. Value at Tc = 25 °C

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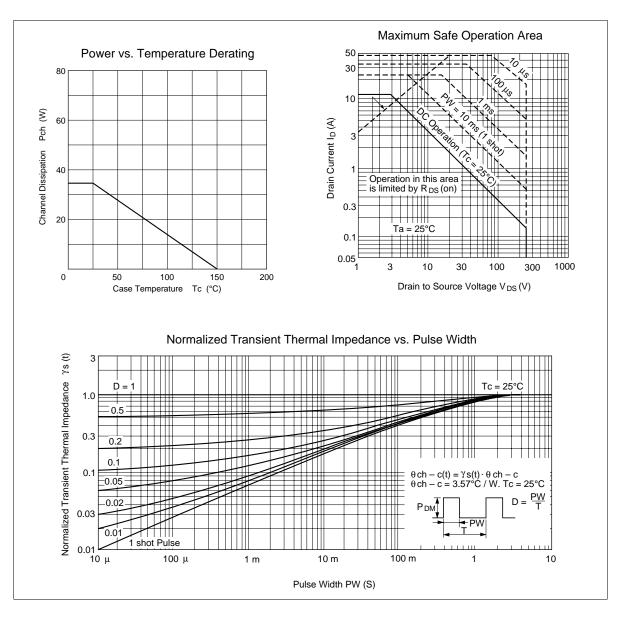
Electrical Characteristics (Ta = 25° C)

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	250	—	_	V	$I_{\rm D} = 10 \text{ mA}, V_{\rm GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	—	—	V	$I_{G} = \pm 100 \ \mu A, V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	250	μA	$V_{\rm DS} = 200 \text{ V}, \text{ V}_{\rm GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0		3.0	V	$I_{\rm D} = 1 \text{ mA}, V_{\rm DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{\text{DS(on)}}$	_	0.23	0.35		$I_{\rm D} = 6 \text{ A}$ $V_{\rm GS} = 10 \text{ V}^{*1}$
Forward transfer admittance	y _{fs}	5.0	8.0	—	S	$I_{\rm D} = 6 \text{ A}$ $V_{\rm DS} = 10 \text{ V}^{*1}$
Input capacitance	Ciss	_	1100	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	440	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	68	_	pF	f = 1 MHz
Turn-on delay time	t _{d(on)}	_	20	_	ns	I _D = 6 A
Rise time	t,	_	65	_	ns	V _{GS} = 10 V
Turn-off delay time	t _{d(off)}	_	100	_	ns	R _L = 5
Fall time	t _f	_	44	_	ns	
Body to drain diode forward voltage	V_{DF}	—	1.0	—	V	$I_F = 12 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	—	200	—	ns	$I_F = 12 \text{ A}, V_{GS} = 0,$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

Note 1. Pulse Test

See characteristic curves of 2SK1761.

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